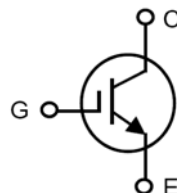


## High Voltage XPT™ IGBT

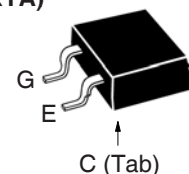
## IXYA12N250CHV IXYH12N250CHV

$$\begin{aligned} V_{CES} &= 2500V \\ I_{C110} &= 12A \\ V_{CE(sat)} &\leq 4.50V \\ t_{fi(typ)} &= 136ns \end{aligned}$$

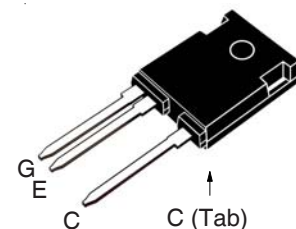


| Symbol                  | Test Conditions                                                                      | Maximum Ratings |                  |
|-------------------------|--------------------------------------------------------------------------------------|-----------------|------------------|
| $V_{CES}$               | $T_J = 25^\circ\text{C to } 175^\circ\text{C}$                                       | 2500            | V                |
| $V_{CGR}$               | $T_J = 25^\circ\text{C to } 175^\circ\text{C}, R_{GE} = 1M\Omega$                    | 2500            | V                |
| $V_{GES}$               | Continuous                                                                           | $\pm 20$        | V                |
| $V_{GEM}$               | Transient                                                                            | $\pm 30$        | V                |
| $I_{C25}$               | $T_C = 25^\circ\text{C}$                                                             | 28              | A                |
| $I_{C110}$              | $T_C = 110^\circ\text{C}$                                                            | 12              | A                |
| $I_{CM}$                | $T_C = 25^\circ\text{C}, 1\text{ms}$                                                 | 80              | A                |
| <b>SSOA<br/>(RBSOA)</b> | $V_{GE} = 15V, T_{VJ} = 150^\circ\text{C}, R_G = 10\Omega$<br>Clamped Inductive Load | $I_{CM} = 48$   | A                |
|                         |                                                                                      | 1500            | V                |
| $P_C$                   | $T_C = 25^\circ\text{C}$                                                             | 310             | W                |
| $T_J$                   |                                                                                      | -55 ... +175    | $^\circ\text{C}$ |
| $T_{JM}$                |                                                                                      | 175             | $^\circ\text{C}$ |
| $T_{stg}$               |                                                                                      | -55 ... +175    | $^\circ\text{C}$ |
| $T_L$                   | Maximum Lead Temperature for Soldering                                               | 300             | $^\circ\text{C}$ |
| $T_{SOLD}$              | 1.6 mm (0.062in.) from Case for 10s                                                  | 260             | $^\circ\text{C}$ |
| $M_d$                   | Mounting Torque (TO-247HV)                                                           | 1.13/10         | Nm/lb.in.        |
| <b>Weight</b>           | TO-263HV                                                                             | 2.5             | g                |
|                         | TO-247HV                                                                             | 6.0             | g                |

TO-263HV (IXYA)



TO-247HV (IXYH)



G = Gate      C = Collector  
E = Emitter    Tab = Collector

### Features

- High Voltage Packages
- High Blocking Voltage
- High Peak Current Capability
- Low Saturation Voltage

### Advantages

- Low Gate Drive Requirement
- High Power Density

### Applications

- Switch-Mode and Resonant-Mode Power Supplies
- Uninterruptible Power Supplies (UPS)
- Laser Generators
- Capacitor Discharge Circuits
- AC Switches

| Symbol        | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified) | Characteristic Values |      |                          |
|---------------|-----------------------------------------------------------------------------|-----------------------|------|--------------------------|
|               |                                                                             | Min.                  | Typ. | Max.                     |
| $BV_{CES}$    | $I_C = 250\mu\text{A}, V_{GE} = 0V$                                         | 2500                  |      | V                        |
| $V_{GE(th)}$  | $I_C = 250\mu\text{A}, V_{CE} = V_{GE}$                                     | 3.0                   |      | 5.0 V                    |
| $I_{CES}$     | $V_{CE} = V_{CES}, V_{GE} = 0V$<br>$T_J = 150^\circ\text{C}$                |                       |      | 10 $\mu\text{A}$<br>3 mA |
| $I_{GES}$     | $V_{CE} = 0V, V_{GE} = \pm 20V$                                             |                       |      | $\pm 100$ nA             |
| $V_{CE(sat)}$ | $I_C = 12A, V_{GE} = 15V$ , Note 1<br>$T_J = 150^\circ\text{C}$             | 3.70<br>5.55          |      | V<br>V                   |

**Symbol Test Conditions**
 $(T_J = 25^\circ\text{C Unless Otherwise Specified})$ 
**Characteristic Values**

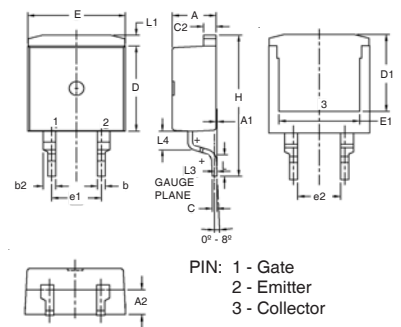
|              |                                                                                                                                                                  | Min. | Typ. | Max.                    |
|--------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|-------------------------|
| $g_{fs}$     | $I_C = 12\text{A}, V_{CE} = 10\text{V}, \text{Note 1}$                                                                                                           | 7    | 12   | S                       |
| $R_{Gi}$     | Gate Input Resistance                                                                                                                                            |      | 7.5  | $\Omega$                |
| $C_{ies}$    | $V_{CE} = 25\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$                                                                                                       |      | 1370 | pF                      |
| $C_{oes}$    |                                                                                                                                                                  |      | 65   | pF                      |
| $C_{res}$    |                                                                                                                                                                  |      | 16   | pF                      |
| $Q_{g(on)}$  | $I_C = 12\text{A}, V_{GE} = 15\text{V}, V_{CE} = 0.5 \cdot V_{CES}$                                                                                              |      | 56   | nC                      |
| $Q_{ge}$     |                                                                                                                                                                  |      | 6    | nC                      |
| $Q_{gc}$     |                                                                                                                                                                  |      | 28   | nC                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 12\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 10\Omega$<br>Note 2  |      | 12   | ns                      |
| $t_{ri}$     |                                                                                                                                                                  |      | 16   | ns                      |
| $E_{on}$     |                                                                                                                                                                  |      | 3.56 | mJ                      |
| $t_{d(off)}$ |                                                                                                                                                                  |      | 167  | ns                      |
| $t_{fi}$     |                                                                                                                                                                  |      | 136  | ns                      |
| $E_{off}$    |                                                                                                                                                                  |      | 1.70 | mJ                      |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b><br>$I_C = 12\text{A}, V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}, R_G = 10\Omega$<br>Note 2 |      | 12   | ns                      |
| $t_{ri}$     |                                                                                                                                                                  |      | 20   | ns                      |
| $E_{on}$     |                                                                                                                                                                  |      | 4.78 | mJ                      |
| $t_{d(off)}$ |                                                                                                                                                                  |      | 195  | ns                      |
| $t_{fi}$     |                                                                                                                                                                  |      | 138  | ns                      |
| $E_{off}$    |                                                                                                                                                                  |      | 1.95 | mJ                      |
| $R_{thJC}$   |                                                                                                                                                                  |      |      | 0.48 $^\circ\text{C/W}$ |
| $R_{thCS}$   | TO-247HV                                                                                                                                                         |      | 0.21 | $^\circ\text{C/W}$      |

**Notes:**

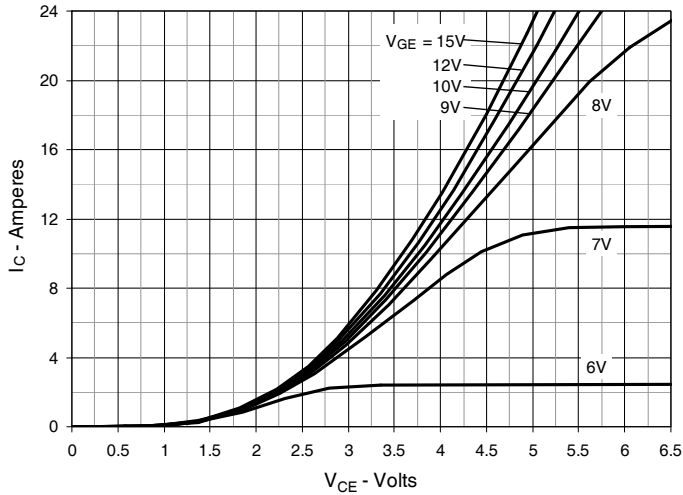
1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .
2. Switching times & energy losses may increase for higher  $V_{CE}(\text{clamp})$ ,  $T_J$  or  $R_G$ .

**ADVANCE TECHNICAL INFORMATION**

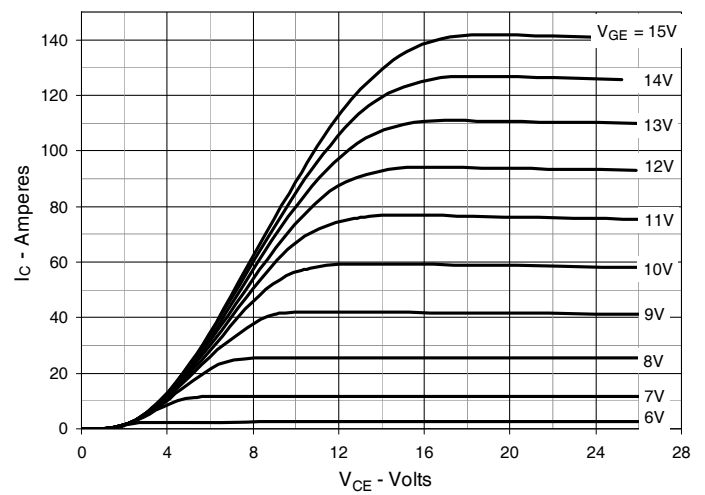
The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

**TO-263HV Outline**


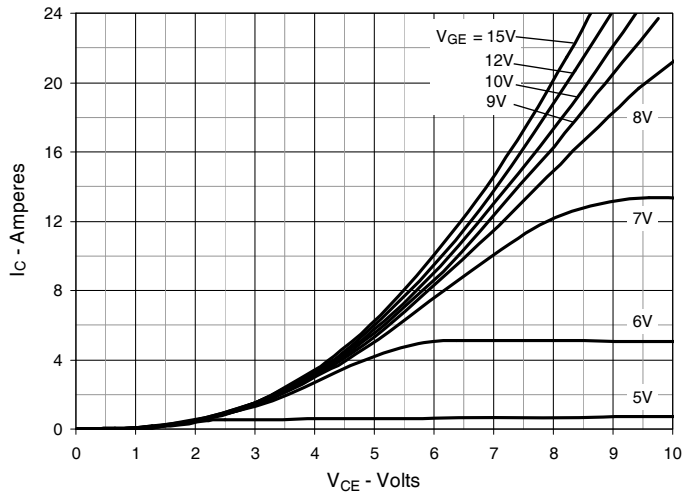
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



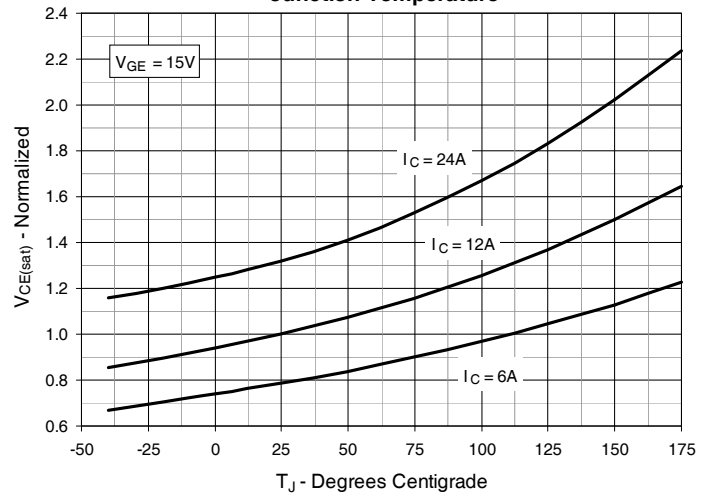
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



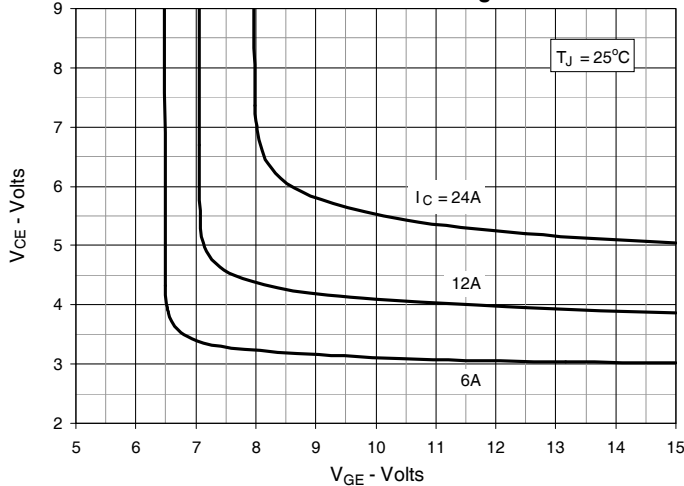
**Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$**



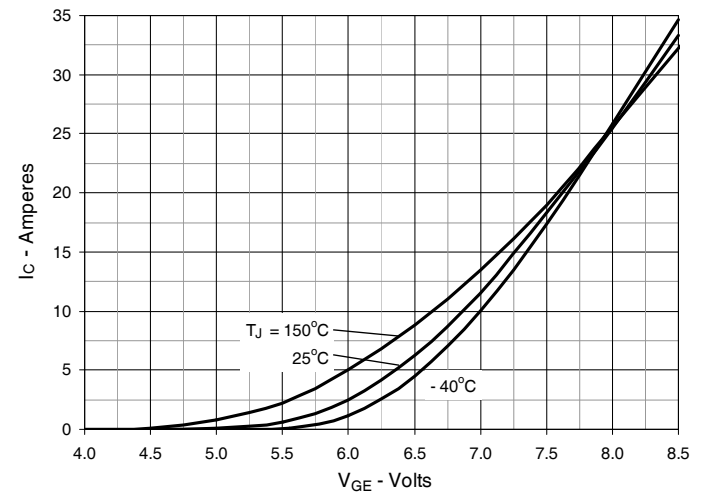
**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**



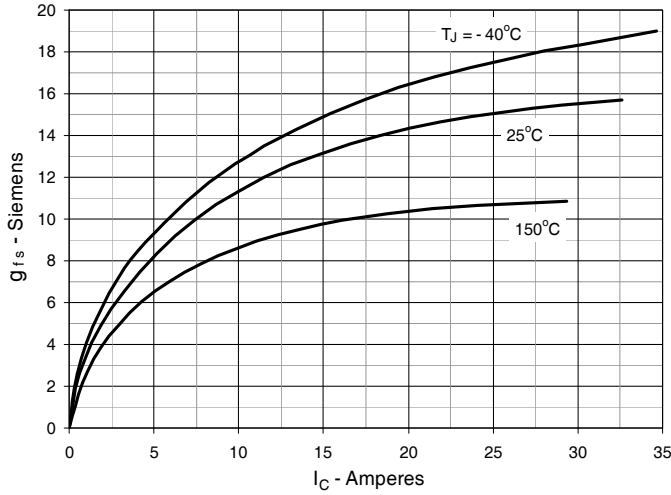
**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**



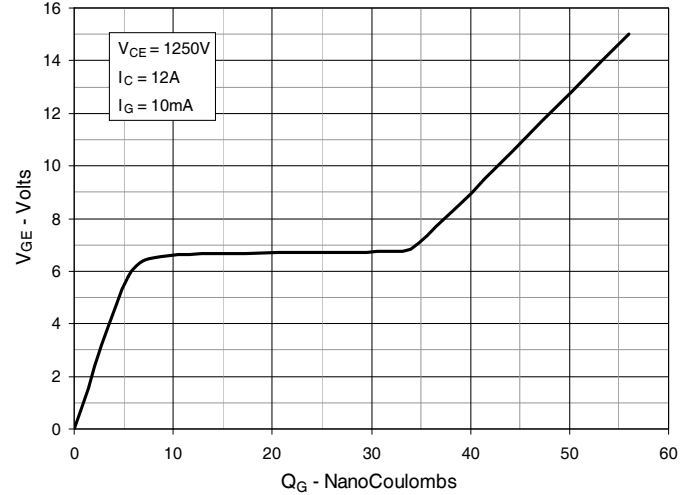
**Fig. 6. Input Admittance**



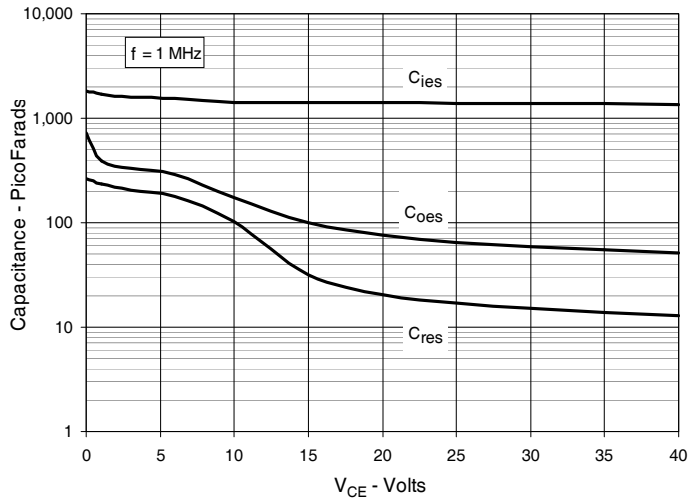
**Fig. 7. Transconductance**



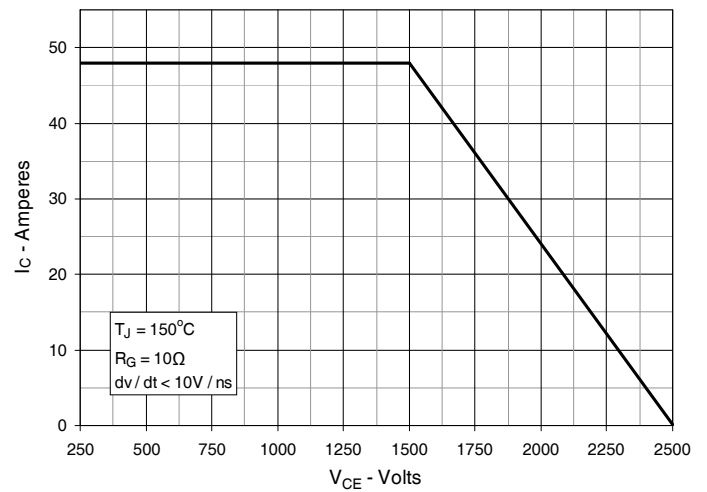
**Fig. 8. Gate Charge**



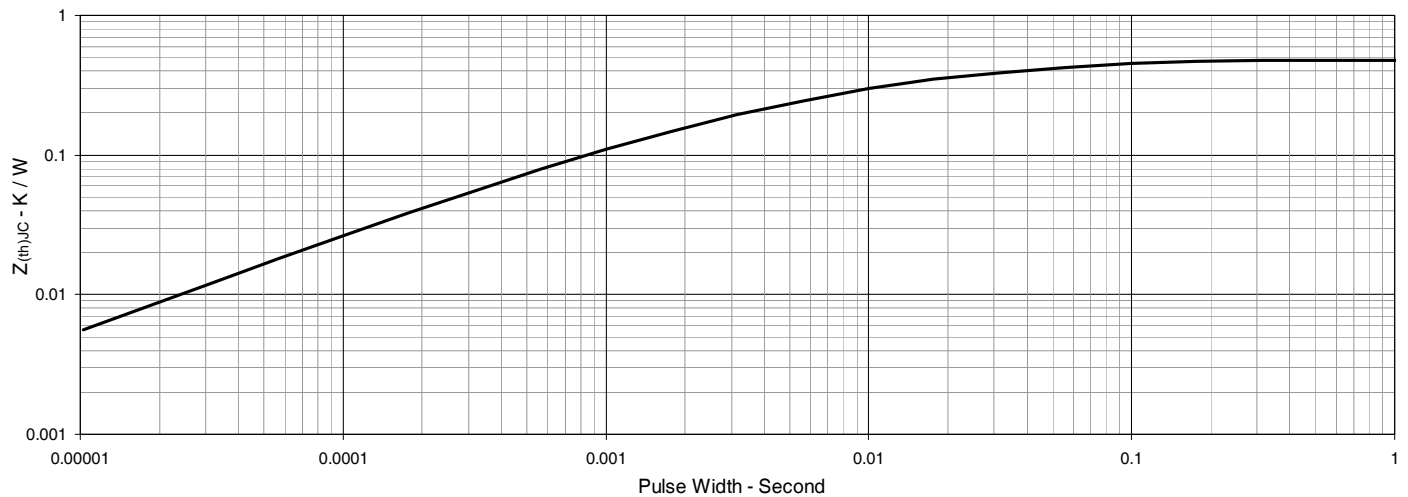
**Fig. 9. Capacitance**

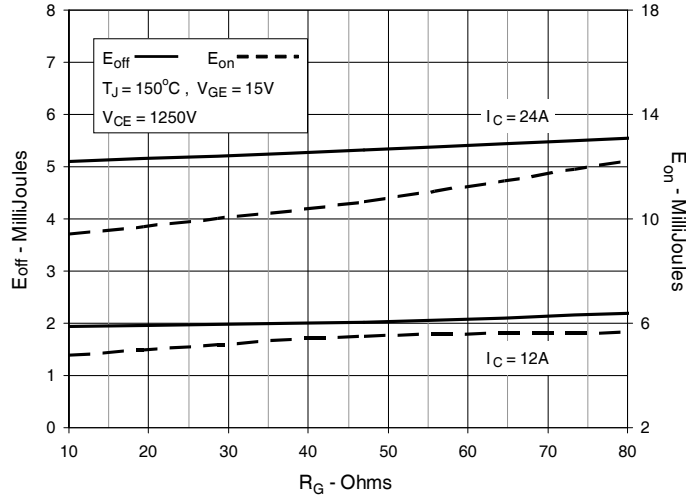
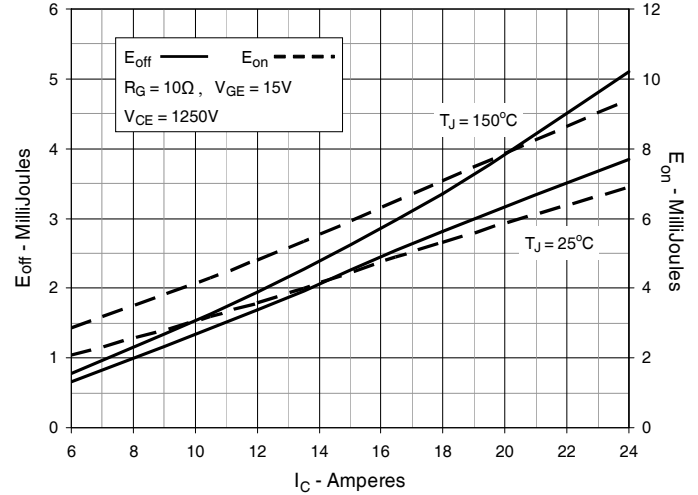
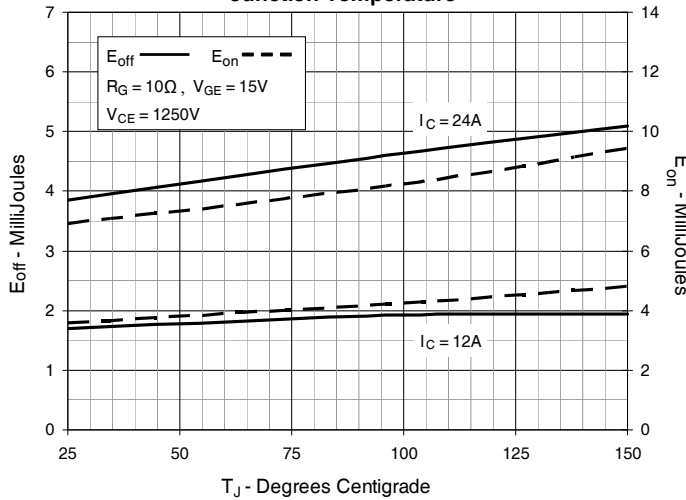
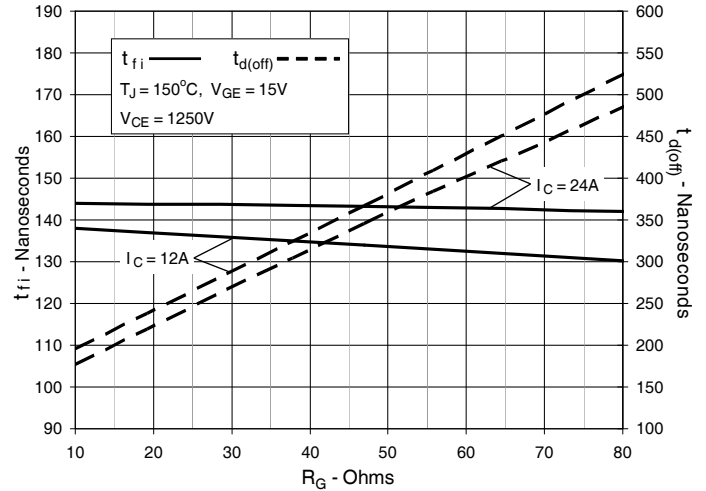
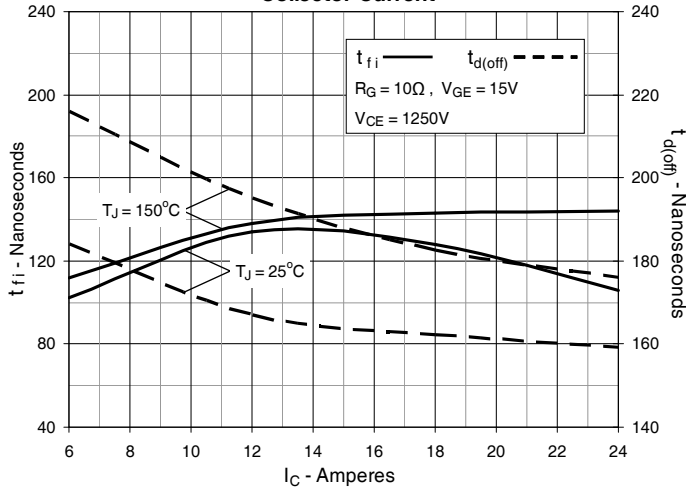
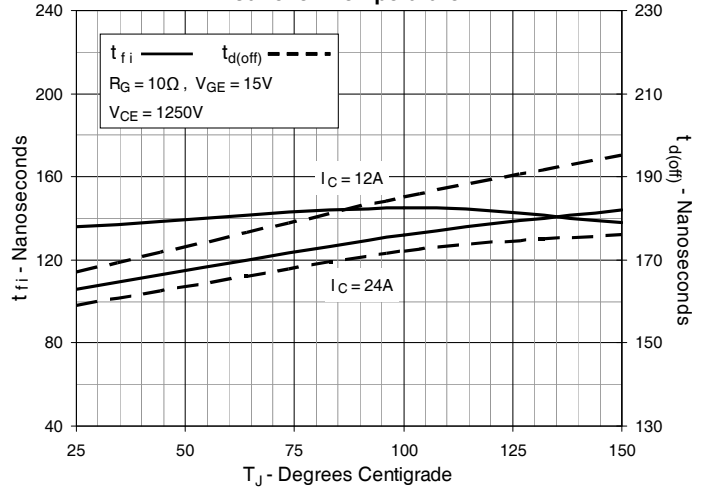


**Fig. 10. Reverse-Bias Safe Operating Area**

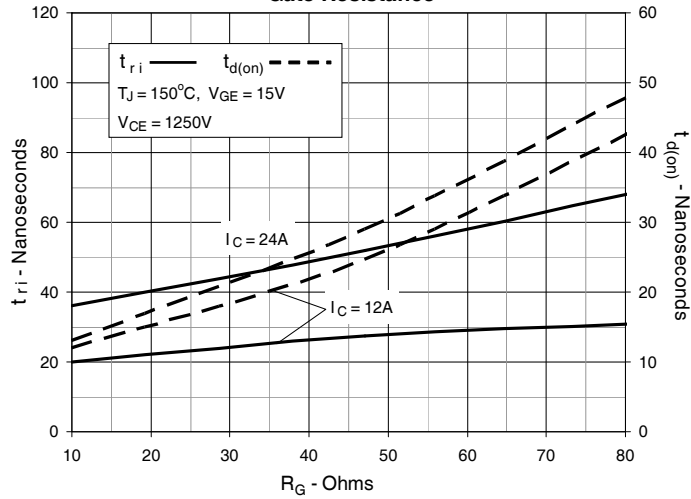


**Fig. 11. Maximum Transient Thermal Impedance**

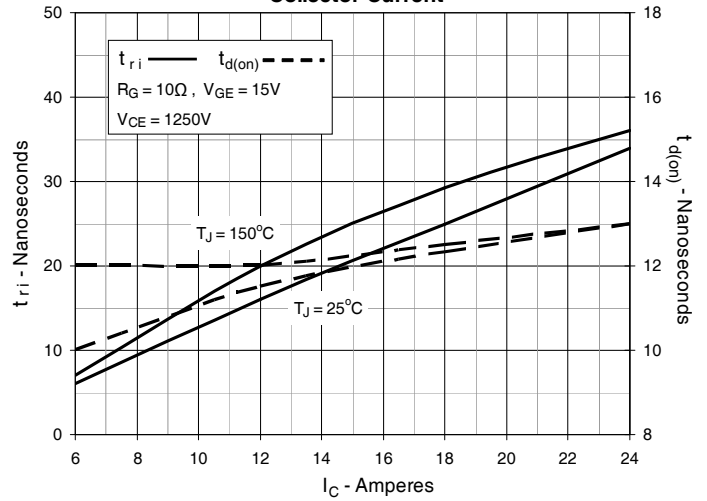


**Fig. 12. Inductive Switching Energy Loss vs. Gate Resistance**

**Fig. 13. Inductive Switching Energy Loss vs. Collector Current**

**Fig. 14. Inductive Switching Energy Loss vs. Junction Temperature**

**Fig. 15. Inductive Turn-off Switching Times vs. Gate Resistance**

**Fig. 16. Inductive Turn-off Switching Times vs. Collector Current**

**Fig. 17. Inductive Turn-off Switching Times vs. Junction Temperature**


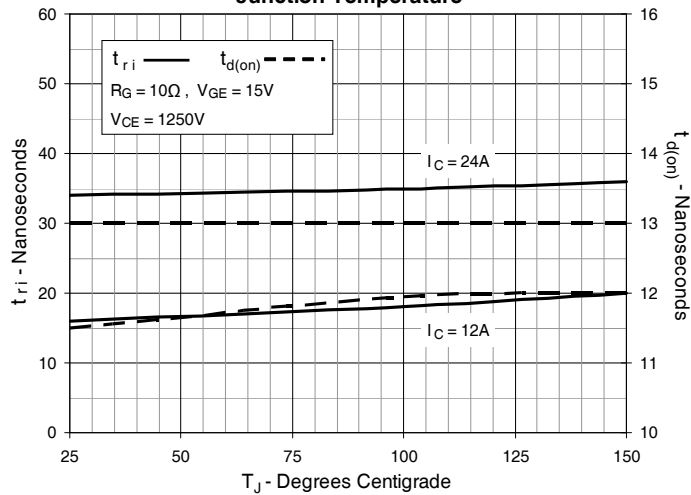
**Fig. 18. Inductive Turn-on Switching Times vs. Gate Resistance**



**Fig. 19. Inductive Turn-on Switching Times vs. Collector Current**



**Fig. 20. Inductive Turn-on Switching Times vs. Junction Temperature**





---

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at [www.littelfuse.com/disclaimer-electronics](http://www.littelfuse.com/disclaimer-electronics).